

# μPC1251, μPC358

R03DS0116EJ0100  
Rev.1.00  
2017.12.25

## Single Power Supply Dual Operational Amplifiers

### DESCRIPTION

μPC1251, μPC358 are dual operational amplifiers designed to operate on a single power supply. The features include low-voltage operation, a common-mode input voltage that range from  $V^-$  (GND) level, an output from a  $V^-$  (GND) level that is determined by the output stage of class C push-pull circuit and a 50 μA(TYP.) constant current, and a low current consumption.

In addition to that, this amplifier can also operate in both positive and negative power supply and can be used extensively in various amplifier circuits.

The μPC1251 is suited for wide operating ambient temperature use due to its temperature expansion type, while μPC358 is for general purposes usage.

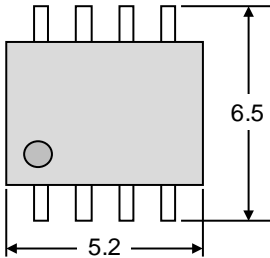
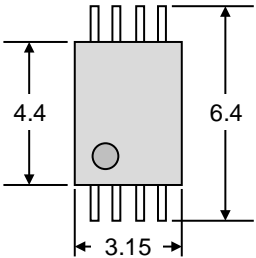
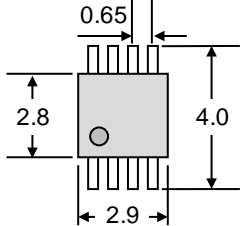
A DC parameter selection that is compatible to operational amplifiers is also available.

μPC451, μPC324 which are quad types with the same circuit configuration are also available under this series of operational amplifiers.

### FEATURES

- Input Offset Voltage  $\pm 2$  mV (TYP.)
- Input Offset Current  $\pm 5$  nA (TYP.)
- Large Signal Voltage Gain 100000 (TYP.)
- Internal Frequency Compensation
- Output Short-Circuit Protection

### Product Lineup

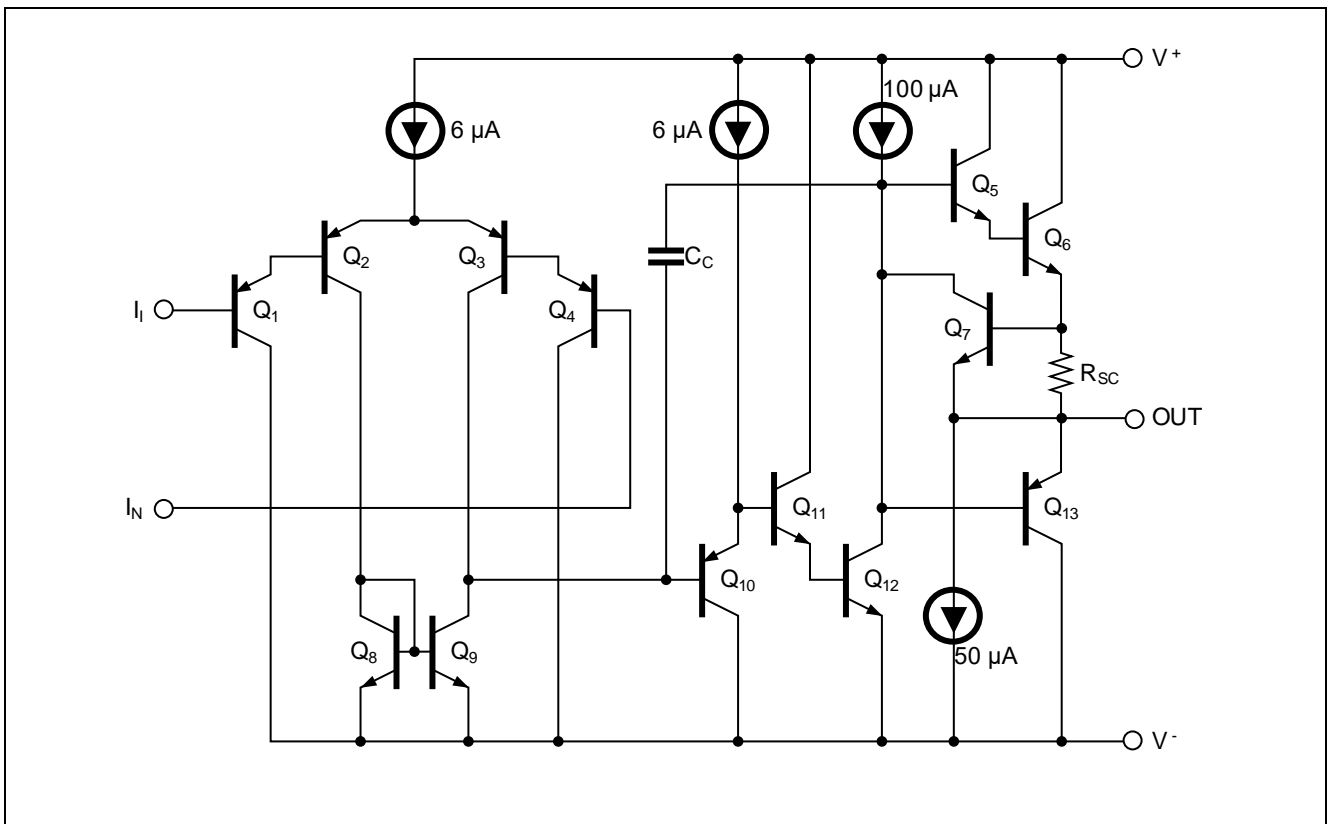
Package	Standard SOP	TSSOP	MSOP
Subject Part Number	μPC1251G2, μPC358G2	μPC1251GR-9LG, μPC358GR-9LG	μPC1251MP-KAA
Outline Comparison	Unit : mm 	Unit : mm 	Unit : mm 
(Mounting Area Ratio)	(100 %)	(60 %)	(34 %)

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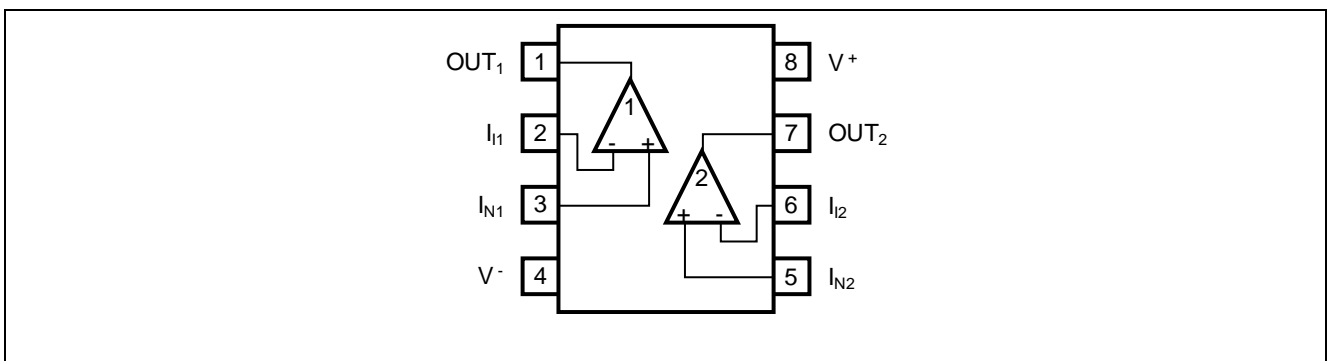
### ORDERING INFORMATION

Part Number	Selected Grade	Package
μPC1251G2-A	Standard	8-pin plastic SOP ( 5.72 mm ( 225 ) )
μPC1251G2(5)-A	DC parameter selection	8-pin plastic SOP ( 5.72 mm ( 225 ) )
μPC358G2-A	Standard	8-pin plastic SOP ( 5.72 mm ( 225 ) )
μPC358G2(5)-A	DC parameter selection	8-pin plastic SOP ( 5.72 mm ( 225 ) )
μPC1251GR-9LG-A	Standard	8-pin plastic TSSOP ( 5.72 mm ( 225 ) )
μPC1251GR(5)-9LG-A	DC parameter selection	8-pin plastic TSSOP ( 5.72 mm ( 225 ) )
μPC1251MP-KAA-A	Standard	8-pin plastic MSOP ( 2.8 × 2.9 )
μPC1251MP(5)-KAA-A	DC parameter selection	8-pin plastic MSOP ( 2.8 × 2.9 )
μPC358GR-9LG-A	Standard	8-pin plastic TSSOP ( 5.72 mm ( 225 ) )
μPC358GR(5)-9LG-A	DC parameter selection	8-pin plastic TSSOP ( 5.72 mm ( 225 ) )

### EQUIVALENT CIRCUIT (1/2 Circuit)



### PIN CONFIGURATION (Marking side)



## ABSOLUTE MAXIMUM RATINGS

(T<sub>A</sub> = 25 °C)

Parameter	Symbol	μPC1251G2, μPC1251G2(5)	μPC358G2, μPC358G2(5)	μPC1251GR, μPC1251GR(5)	μPC1251MP, μPC1251MP(5)	μPC358GR, μPC358GR(5)	Unit	
Voltage between V+ and V- <small>Note1</small>	V <sup>+</sup> - V <sup>-</sup>	-0.3 ~ +32						V
Differential Input Voltage	V <sub>ID</sub>	±32						V
Input Voltage <small>Note2</small>	V <sub>I</sub>	V <sup>-</sup> -0.3 ~ V <sup>-</sup> +32						V
Output applied Voltage <small>Note3</small>	V <sub>o</sub>	V <sup>-</sup> -0.3 ~ V <sup>+</sup> +0.3						V
Total Power Dissipation <small>Note4</small>	P <sub>T</sub>	440						mW
Output Short Circuit Duration <small>Note5</small>	t <sub>s</sub>	Indefinite						s
Operating Ambient Temperature	T <sub>A</sub>	-40 ~ +85	-20 ~ +80	-40 ~ +125		-40 ~ +85	°C	
Storage Temperature	T <sub>stg</sub>	-55 ~ +125		-55 ~ +150		-55 ~ +125	°C	

- [Note]**
- Note that reverse connections of the power supply may damage the ICs.
  - The input voltage is allowed to input without damage or destruction independent of the magnitude of V+. Either input signal is not allowed to go negative by more than 0.3 V. In addition, the input voltage that operates normally as an operational amplifier is within the Common Mode Input Voltage range of an electrical characteristic.
  - A range where input voltage can be applied to an output pin externally with no deterioration or damage to the feature (characteristic). The input voltage can be applied regardless of the electric supply voltage. This specification which includes the transition state such as electric power ON/OFF must be kept.
  - This is the value when the glass epoxy substrate (size: 100 mm x 100 mm, thickness: 1 mm, 15% of the substrate area where only one side is copper foiled is filling wired) is mounted.  
Note that restrictions will be made to the following conditions for each product, and the derating ratio depending on the operating ambient temperature.

μPC1251G2 : Derate at -4.4 mW/°C when T<sub>A</sub> > 25 °C  
(Junction - ambient thermal resistance R<sub>th(J-A)</sub> = 227°C/W)

μPC358G2 : Derate at -4.4 mW/°C when T<sub>A</sub> > 25 °C  
(Junction - ambient thermal resistance R<sub>th(J-A)</sub> = 227°C/W)

μPC1251GR-9LG : Derate at -5.5 mW/°C when T<sub>A</sub> > 69 °C  
(Junction - ambient thermal resistance R<sub>th(J-A)</sub> = 183°C/W)

μPC1251MP-KAA : Derate at -4.8 mW/°C when T<sub>A</sub> > 58 °C  
(Junction - ambient thermal resistance R<sub>th(J-A)</sub> = 208°C/W)

μPC358GR-9LG : Derate at -5.5 mW/°C when T<sub>A</sub> > 44 °C  
(Junction - ambient thermal resistance R<sub>th(J-A)</sub> = 183°C/W)

- Short circuits from the output to V<sup>+</sup> can cause destruction. Pay careful attention to the total power dissipation by not exceeding the absolute maximum ratings, **Note 4**.

## RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Power Supply Voltage (Split)	V <sup>±</sup>	±1.5		±15	V
Power Supply Voltage (V <sup>-</sup> = GND)	V <sup>+</sup>	+3		+30	V

## ELECTRICAL CHARACTERISTICS

μPC1251, μPC358 (T<sub>A</sub> = 25 °C, V<sup>+</sup> = +5 V, V<sup>-</sup> = GND)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit	Test Condition
Input Offset Voltage	V <sub>IO</sub>		±2	±7	mV	R <sub>S</sub> = 0 Ω
Input Offset Current	I <sub>IO</sub>		±5	±50	nA	
Input Bias Current <sup>Note 6</sup>	I <sub>B</sub>		14	250	nA	
Large Signal Voltage Gain	A <sub>V</sub>	25000	100000			R <sub>L</sub> ≥ 2 kΩ
Circuit Current <sup>Note 7</sup>	I <sub>CC</sub>		0.7	1.2	mA	R <sub>L</sub> = ∞, I <sub>O</sub> = 0 A
Common Mode Rejection Ratio	CMR	65	70		dB	
Supply Voltage Rejection Ratio	SVR	65	100		dB	
Output Voltage Swing	V <sub>O</sub>	0		V <sup>+</sup> -1.5	V	R <sub>L</sub> = 2 kΩ (Connected to GND)
Common Mode Input Voltage Range	V <sub>ICM</sub>	0		V <sup>+</sup> -1.5	V	
Output Source Current	I <sub>O SOURCE</sub>	20	40		mA	V <sub>IN(+)</sub> = +1 V, V <sub>IN(-)</sub> = 0 V
Output Sink Current	I <sub>O SINK1</sub>	10	20		mA	V <sub>IN(-)</sub> = +1 V, V <sub>IN(+)</sub> = 0 V
	I <sub>O SINK2</sub>	12	50		μA	V <sub>IN(-)</sub> = +1 V, V <sub>IN(+)</sub> = 0 V, V <sub>O</sub> = 200 mV
Channel Separation			120		dB	f = 1 ~ 20 kHz

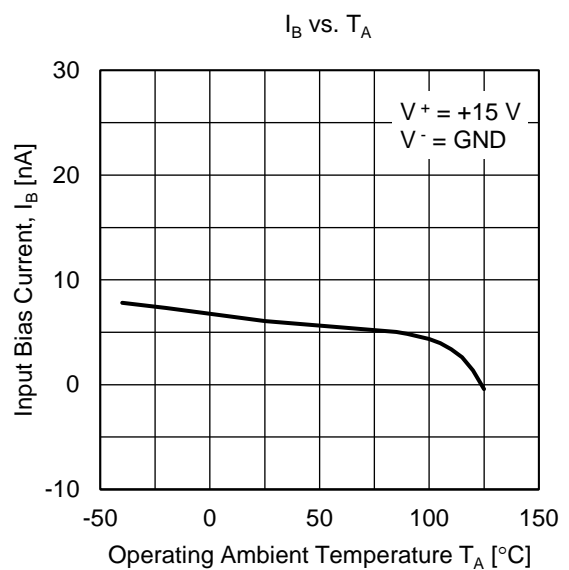
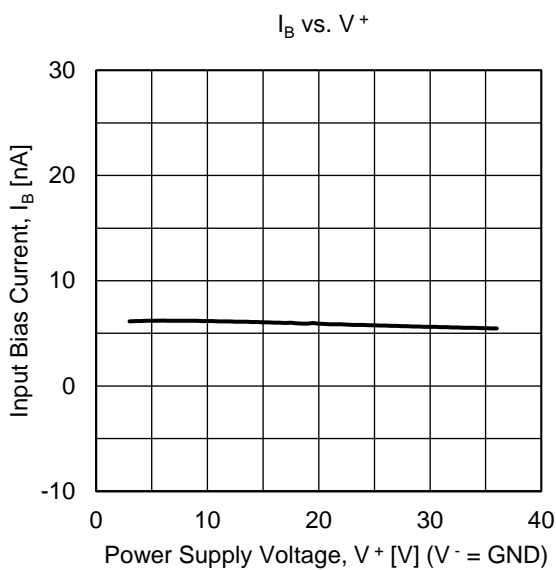
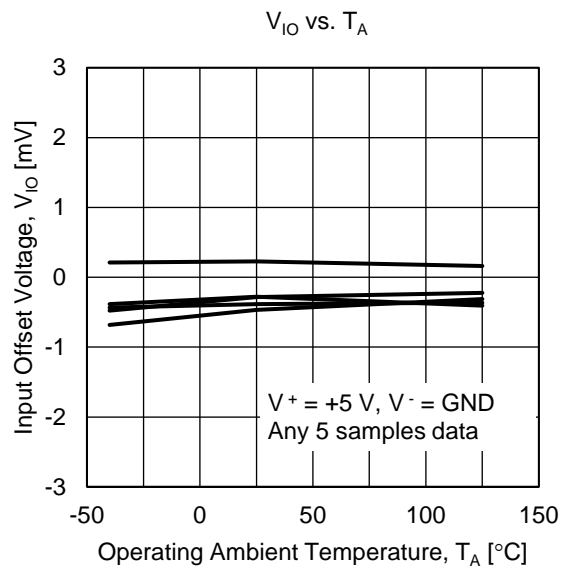
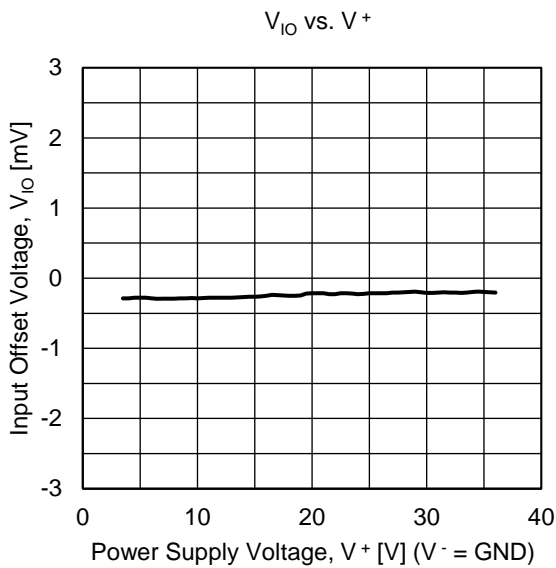
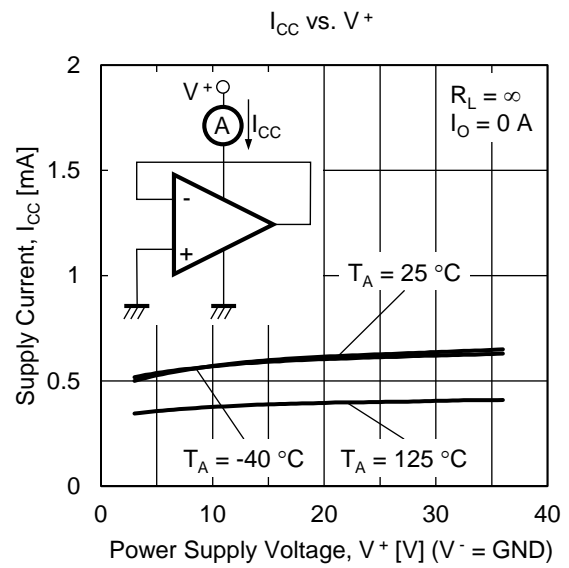
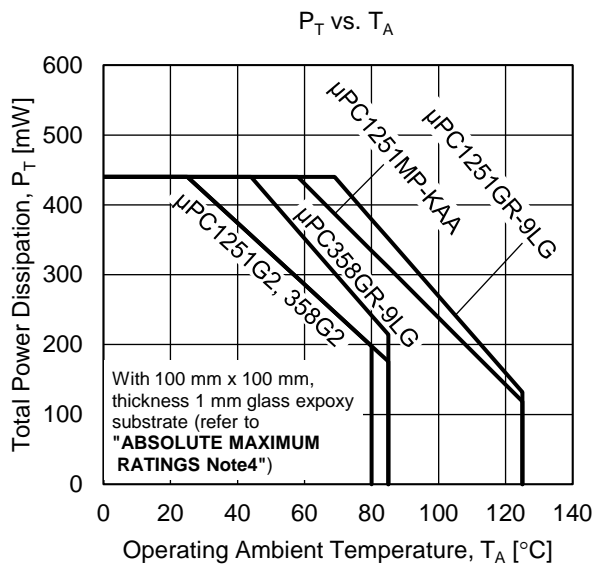
μPC1251 (5), μPC358 (5) (T<sub>A</sub> = 25 °C, V<sup>+</sup> = +5 V, V<sup>-</sup> = GND)

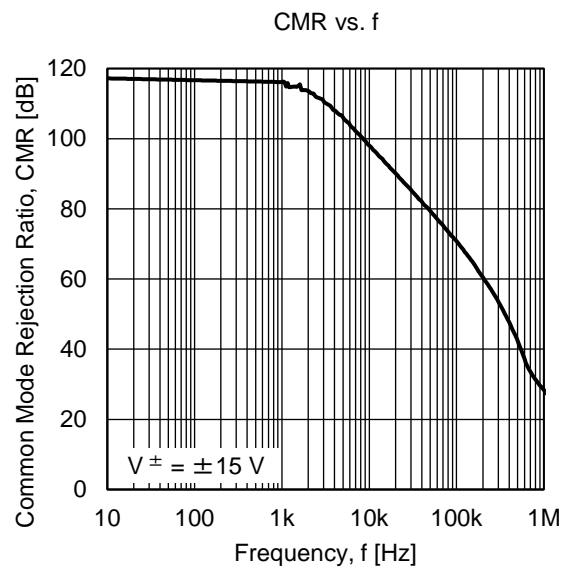
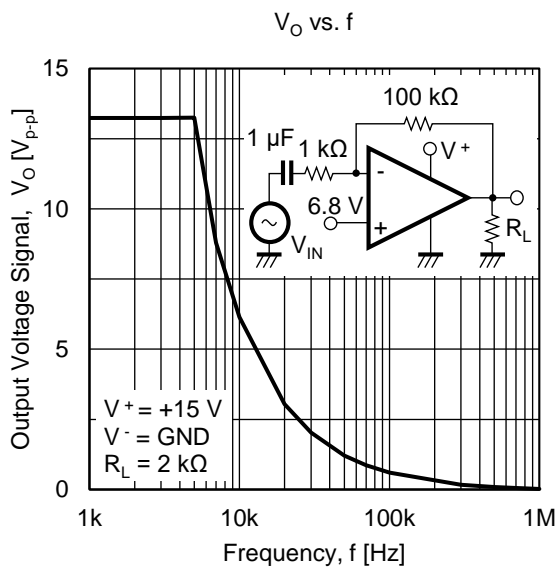
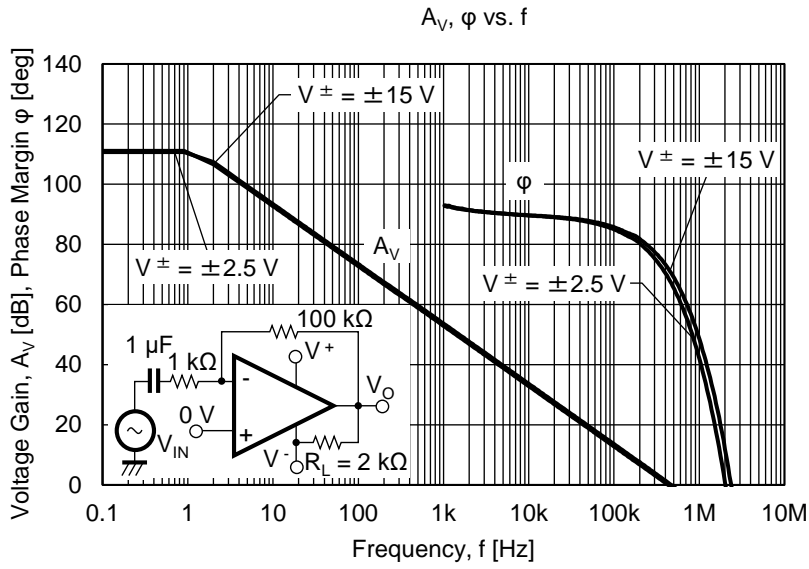
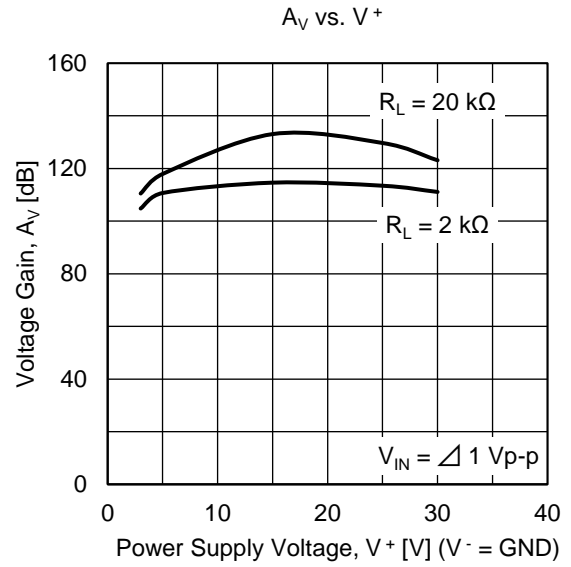
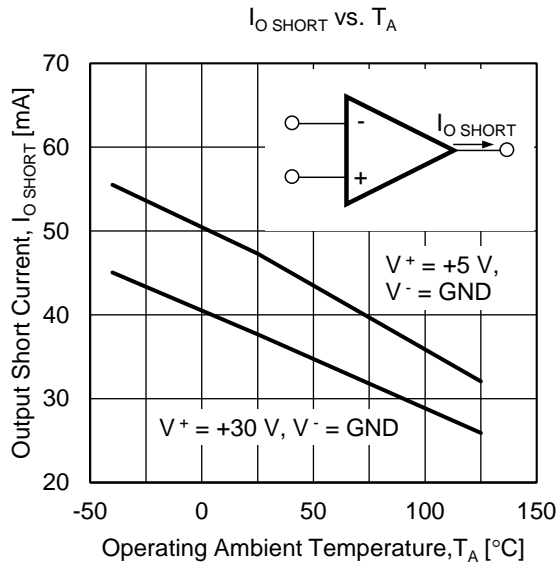
Parameter	Symbol	MIN.	TYP.	MAX.	Unit	Test Condition
Input Offset Voltage	V <sub>IO</sub>		±2	±3	mV	R <sub>S</sub> = 0 Ω
Input Offset Current	I <sub>IO</sub>		±5	±50	nA	
Input Bias Current <sup>Note 6</sup>	I <sub>B</sub>		14	60	nA	
Large Signal Voltage Gain	A <sub>V</sub>	50000	100000			R <sub>L</sub> ≥ 2 kΩ
Circuit Current <sup>Note 7</sup>	I <sub>CC</sub>		0.7	0.9	mA	R <sub>L</sub> = ∞, I <sub>O</sub> = 0 A
Common Mode Rejection Ratio	CMR	65	70		dB	
Supply Voltage Rejection Ratio	SVR	65	100		dB	
Output Voltage Swing	V <sub>O</sub>	0		V <sup>+</sup> -1.5	V	R <sub>L</sub> = 2 kΩ (Connected to GND)
Common Mode Input Voltage Range	V <sub>ICM</sub>	0		V <sup>+</sup> -1.4	V	
Output Source Current	I <sub>O SOURCE</sub>	30	40		mA	V <sub>IN(+)</sub> = +1 V, V <sub>IN(-)</sub> = 0 V
Output Sink Current	I <sub>O SINK1</sub>	15	20		mA	V <sub>IN(-)</sub> = +1 V, V <sub>IN(+)</sub> = 0 V
	I <sub>O SINK2</sub>	30	50	70	μA	V <sub>IN(-)</sub> = +1 V, V <sub>IN(+)</sub> = 0 V, V <sub>O</sub> = 200 mV
Channel Separation			120		dB	f = 1 ~ 20 kHz

**[Note]** 6. The absolute value of the input bias current is small, thus the direction of the current flowing from the inside of the IC may be reversed due to variations in the product during high temperature.

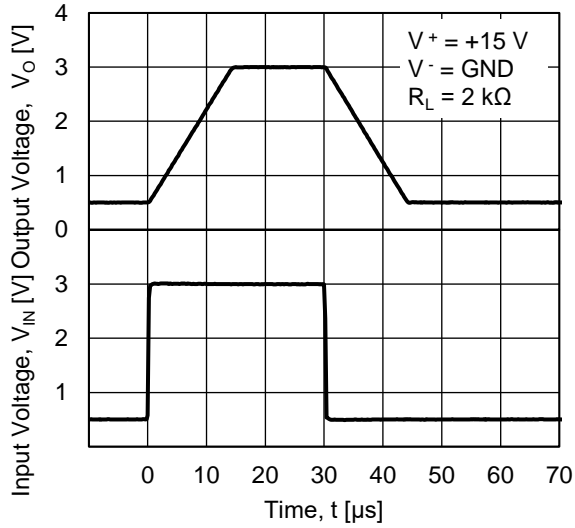
7. This is a current that flows in the internal circuit. This current will flow irrespective of the channel used.

TYPICAL PERFORMANCE CHARACTERISTICS (T<sub>A</sub> = 25 °C, TYP.) (Reference Value)

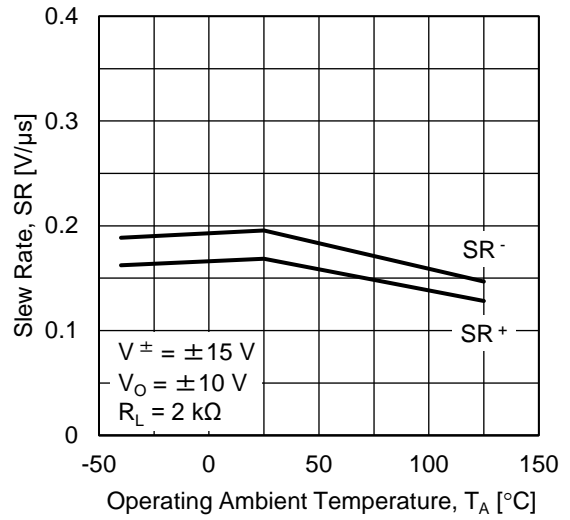




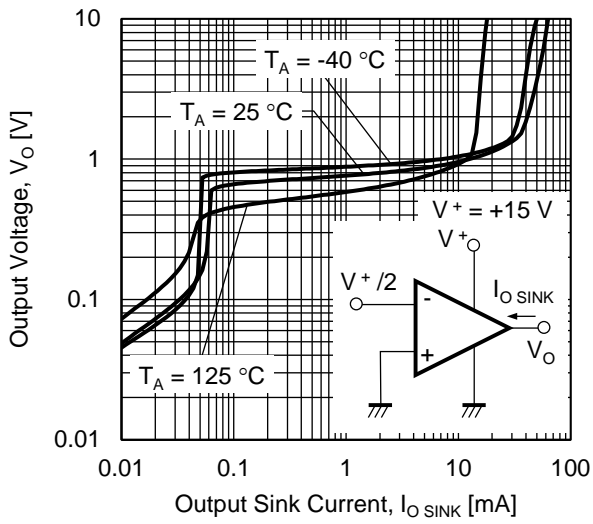
Pulse Response



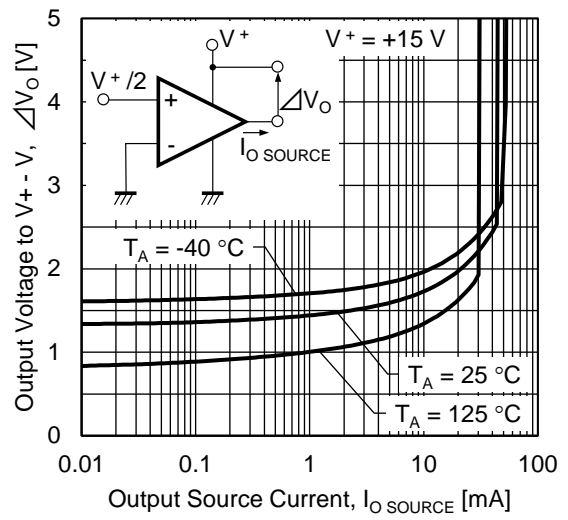
SR -  $T_A$



$V_O$  vs.  $I_{O \text{ SINK}}$



$\Delta V_O$  vs.  $I_{O \text{ SOURCE}}$

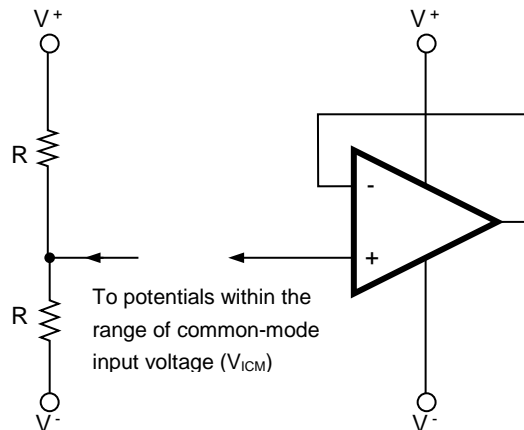


## USE WITH PRECAUTIONS

- **The process of unused circuits**

If there is an unused circuit, the following connection is recommended.

### Process example of unused circuits



**Remark:** A midpoint potential of  $V^+$  and  $V^-$  is applied to this example.

- **Ratings of input/output pin voltage**

When the voltage of input/output pin exceeds the absolute maximum rating, it may cause degradation of characteristics or damage, by a conduction of a parasitic diode within an IC. In addition, if the input pin is lower than  $V^-$ , or the output pin exceeds the power supply voltage, it is recommended to make a clamp circuit using a diode with low forward voltage (e.g.: Schottky diode) as protection.

- **Range of common-mode input voltage**

When the supply voltage does not meet the condition of electrical characteristics, the range of common-mode input voltage is as follows.

$V_{ICM}$  (TYP.):  $V^-$  to  $V^+ - 1.5$  (V) ( $T_A = 25^\circ\text{C}$ ).

During designing, do include some tolerance by considering temperature characteristics and etc.

- **Maximum output voltage**

The TYP. value range of the maximum output voltage when the supply voltage does not meet the condition of electrical characteristics is as follows:

$V_{om+}$  (TYP.):  $V^+ - 1.5$  (V) ( $T_A = 25^\circ\text{C}$ ),  $V_{om-}$  (TYP.) ( $I_{O\ SINK} \leq 50\ \mu\text{A}$ ): Approx.  $V^-$  (V) ( $T_A = 25^\circ\text{C}$ ).

During designing, include some tolerance such as characteristics variation and temperature characteristics consideration and so forth. In addition, also note that the output voltage range ( $V_{om+} - V_{om-}$ ) will become narrow when an output current increases.

- **Operation of output**

This IC output level consist of a class C push-pull. Therefore, when a load resistance is connected to the midpoint potential of  $V^+$ ,  $V^-$ , a crossover distortion occurs during the transition state of output current flow direction (source, sink).

- **Handling of ICs**

When stress is added to the ICs due to warpage or bending of a board, the characteristic may fluctuates due to piezoelectric effect. Therefore, pay attention to warpage or bending of a board.

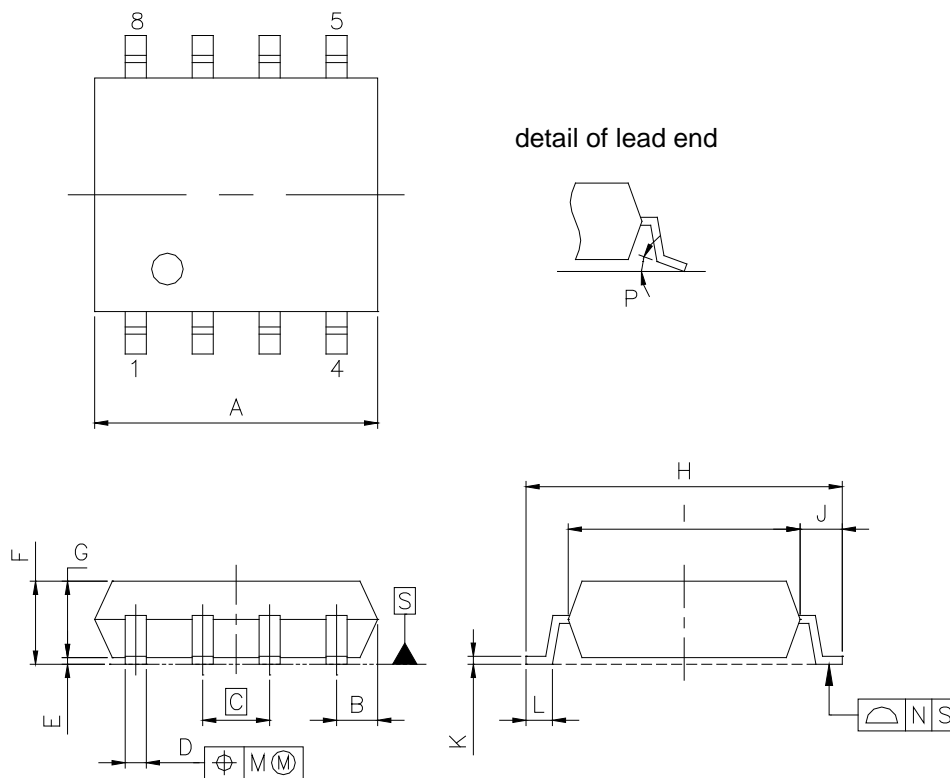


## PACKAGE DRAWINGS

### 8-PIN PLASTIC SOP

JEITA Package code	RENESAS code	Previous code	MASS (TYP.) [g]
P-SOP8-0225-1.27	PRSP0008DL-A	S8GM-50-225B	0.08

Unit: mm



#### NOTE

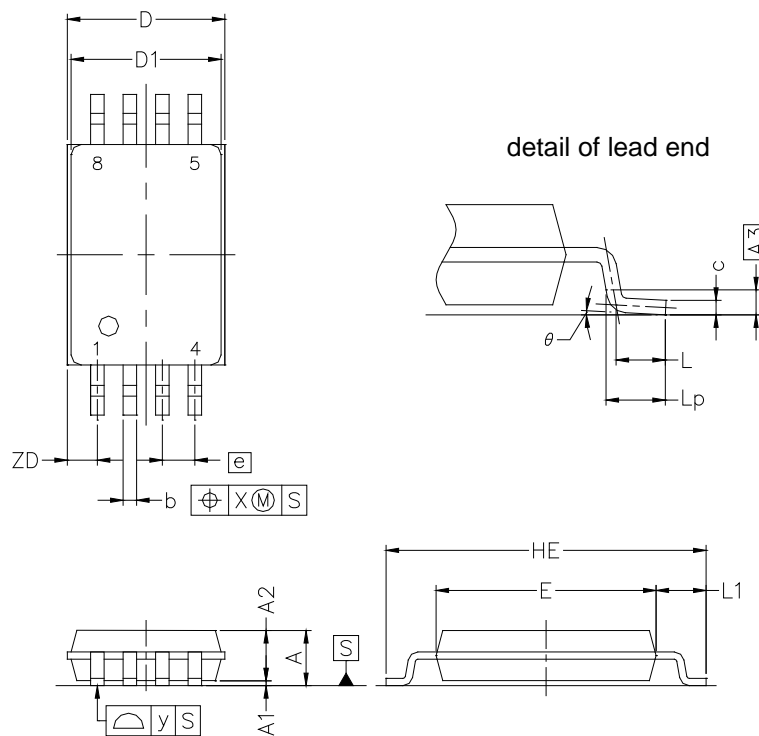
Each lead centerline is located within 0.12 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
A	5.2 <sup>+0.17</sup> / <sub>-0.20</sub>
B	0.78 MAX
<span style="border: 1px solid black; padding: 2px;">C</span>	1.27 (T.P)
D	0.42 <sup>+0.08</sup> / <sub>-0.07</sub>
E	0.1 ±0.1
F	1.59 ±0.21
G	1.49
H	6.5 ±0.3
I	4.4 ±0.15
J	1.1 ±0.2
K	0.17 <sup>+0.08</sup> / <sub>-0.07</sub>
L	0.6 ±0.2
M	0.12
N	0.10
P	3° <sup>+7°</sup> / <sub>-3°</sub>

8-PIN PLASTIC TSSOP

JEITA Package code	RENESAS code	Previous code	MASS(TYP.) [g]
P-TSSOP8-0225-0.65	PTSP0008JD-A	P8GR-65-9LG	—

Unit : mm



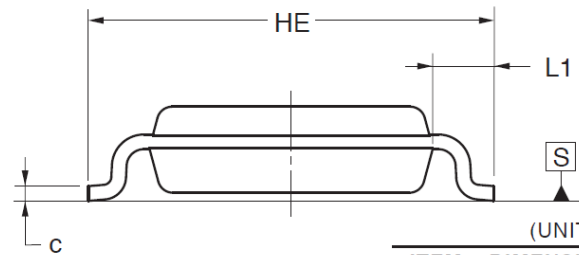
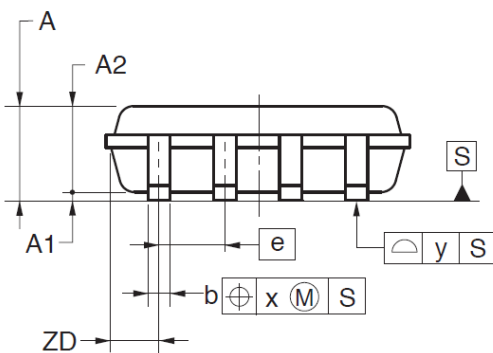
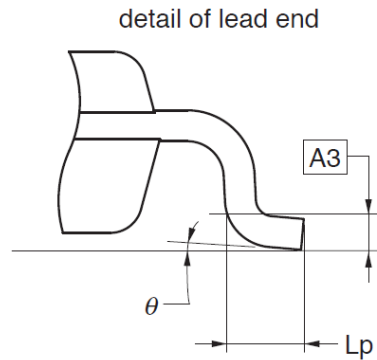
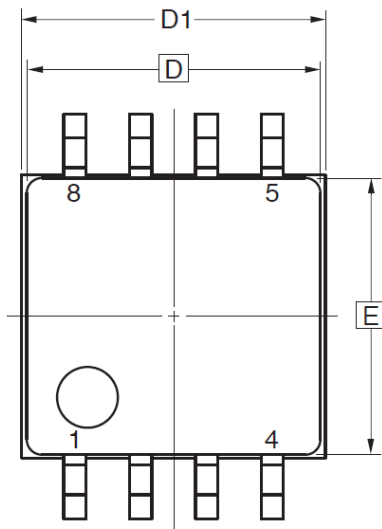
**NOTE**

Each lead centerline is located within 0.10 mm of its true position at maximum material condition.

ITEM	MILLIMETERS
D	3.15 ±0.15
D1	3.00 ±0.10
E	4.40 ±0.10
HE	6.40 ±0.20
A	1.20 MAX.
A1	0.10 ±0.05
A2	1.00 ±0.05
A3	0.25
b	0.24 <sup>+0.06</sup> / <sub>-0.05</sub>
c	0.145 ±0.055
L	0.5
Lp	0.60 ±0.15
L1	1.00 ±0.20
θ	3° <sup>+5°</sup> / <sub>-3°</sub>
e	0.65
x	0.10
y	0.10
ZD	0.60

8-PIN PLASTIC MSOP

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-TSSOP8-2.8x2.9-0.65	PTSP0008JF-A	P8MP-65-KAA-1	0.02



(UNIT:mm)

ITEM	DIMENSIONS
D	2.90
D1	3.00±0.20
E	2.80
HE	4.00±0.20
e	0.65
b	0.22±0.05
A	1.03 MAX.
A1	0.08±0.05
A2	0.85±0.05
A3	0.25
L1	0.60±0.20
c	0.145 <sup>+0.05</sup> <sub>-0.03</sub>
Lp	0.37±0.10
x	0.10
y	0.10
θ	3° <sup>+5°</sup> <sub>-3°</sub>
ZD	0.525

**NOTE**

Each lead centerline is located within 0.10 mm of its true position at maximum material condition.

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